AZ100LVEL16VT

ARIZONA MICROTEK, INC.

ECL/PECL Oscillator Gain Stage & Buffer with Selectable Enable

FEATURES

- High Bandwidth for ≥1GHz
- **Similar Operation as AZ100LVEL16VR Except in Disabled Condition: Q_{HG} is High**
- Operating Range of 3.0V to 5.5V
- Minimizes External Components
- Selectable Enable Polarity and Threshold (CMOS/TTL or PECL)
- Available in a 3x3 mm or 2x2 mm MLP Package

PACKAGE AVAILABILITY

PACKAGE	PART NO.	MARKING
MLP 8 (2x2x.9)	AZ100LVEL16VTMA	TMA
MLP 8 (2x2x.9)	AZ100LVEL16VTMAR1	TMA
MLP 8 (2x2x.75)	AZ100LVEL16VTNA	TNA
MLP 8 (2x2x.75)	AZ100LVEL16VTNAR1	TNA
MLP 8 (2x2x.9)	AZ100LVEL16VTMB	TMB
MLP 8 (2x2x.9)	AZ100LVEL16VTMBR1	TMB
MLP 8 (2x2x.75)	AZ100LVEL16VTNB	TNB
MLP 8 (2x2x.75)	AZ100LVEL16VTNBR1	TNB
MLP 16	AZ100LVEL16VTL	AZM16T
MLP 16 T&R	AZ100LVEL16VTLR1	AZM16T
MLP 16 T&R	AZ100LVEL16VTLR2	AZM16T
DIE	AZ100LVEL16VTX	N/A

DESCRIPTION

The AZ100LVEL16VT is a specialized oscillator gain stage with high gain output buffer including an enable. The $Q_{HG}/\overline{Q}_{HG}$ outputs have a voltage gain several times greater than the $Q/\overline{Q}$ outputs.

MLP 16, 3x3 mm Package (L) or DIE (X)

The AZ100LVEL16VTL provides a selectable enable that allows continuous oscillator operation. See truth table below for enable function. If Enable pull-up is desired in the CMOS mode, an external ≤20 kΩ resistor connecting EN to V_{CC} will override the on-chip pull-down resistor. When disabled the Q_{HG} output is forced high and the $\overline{Q}_{HG}$ output is forced low. The AZ100LVEL16VT also provides a V_{BB} and 470 Ω internal bias resistors from D to V_{BB} and $\overline{D}$ to V_{BB}. The V_{BB} pin can support 1.5 mA sink/source current. Bypassing V_{BB} to ground with a 0.01 µF capacitor is recommended.

The outputs Q and $\overline{Q}$ each have a selectable on-chip pull-down current source. See truth table below for current source functions. External resistors may also be used to increase pull-down current to a maximum total of 25 mA.

Outputs Q_{HG} and $\overline{Q}_{HG}$ each have an optional on-chip pull-down current source of 10 mA. When pad/pin V_{EEP} is left open (NC), the output current sources are disabled and the Q_{HG} /$\overline{Q}_{HG}$ operate as standard PECL/ECL. When V_{EEP} is connected to V_{EE}, the current sources are activated. The Q_{HG} /$\overline{Q}_{HG}$ pull-down current can be decreased, by using a resistor to connect V_{EEP} to V_{EE}. (See graph on page 5)

MLP 8, 2x2 mm Package (M,N) with A & B Bonding Options

The MLP 8, 2x2mm versions of the AZ100LVEL16VT operate in the PECL/ECL mode with an enable input (EN) controlling the Q_{HG} /$\overline{Q}_{HG}$ outputs. When the EN input is LOW, the $\overline{Q}$ and Q_{HG} /$\overline{Q}_{HG}$ outputs follow the input. When EN is HIGH, the Q_{HG} output is forced high and the $\overline{Q}_{HG}$ output is forced low.

The Q, Q_{HG}, and $\overline{Q}_{HG}$ current sources are disabled, while the $\overline{Q}$ output operates with a 4 mA current source to VEE. This is accomplished by internal bonding of CS-SEL, EN-SEL and V_{EEP}.

For the MLP 8, 2x2mm version B, the $\overline{D}$ input is internally tied directly to the VBB pin and the D input is tied to the VBB pin through a 470 Ω internal bias resistor. In the MLP 8, 2x2mm version A, both D and $\overline{D}$ inputs are brought out and tied to the VBB pin through 470 Ω internal bias resistors.

NOTE: Specifications in the ECL/PECL tables are valid when thermal equilibrium is established.

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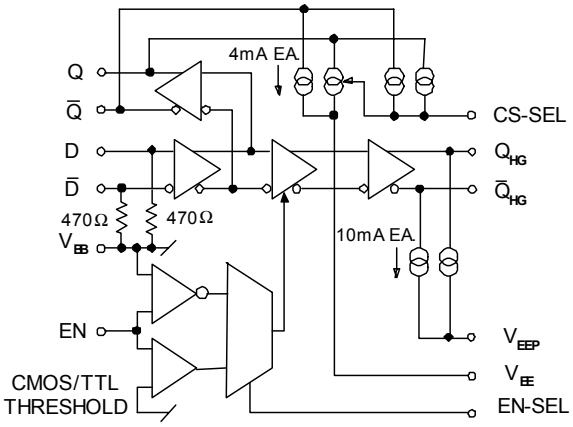
ENABLE TRUTH TABLE

EN-SEL (MLP 16 or DIE)	EN	Q/$\overline{Q}$	Q_{HG}	$\overline{Q}_{HG}$
NC	PECL Low, V_{EE} or NC	Data	Data	Data
NC	PECL High or V_{CC}	Data	High	Low
V_{EE}*	CMOS Low or V_{EE}	Data	High	Low
V_{EE}*	CMOS High or V_{CC}	Data	Data	Data
V_{EE}*	NC, no external pull-up	Data	High	Low
V_{EE}*	NC, with ≤20kΩ to V_{CC}	Data	Data	Data

*Connections to V_{CC} or V_{EE} must be less than 1Ω.

PIN DESCRIPTION

PIN	FUNCTION
D/$\overline{D}$	Data Inputs
Q/$\overline{Q}$	Data Outputs
Q_{HG}/$\overline{Q}_{HG}$	Data Outputs w/High Gain
V_{BB}	Reference Voltage Output
EN-SEL	Selects Enable Logic
EN	Enable Input
CS-SEL	Selects Q and $\overline{Q}$ Current Source Magnitude
V_{EEP}	Optional Q_{HG} and $\overline{Q}_{HG}$ Current Sources
V_{EE}	Negative Supply
V_{CC}	Positive Supply



MLP16

CURRENT SOURCE TRUTH TABLE (MLP 16 or DIE)

CS-SEL	Q	$\overline{Q}$
NC	4mA typ.	4mA typ.
V_{EE}*	8mA typ.	8mA typ.
V_{CC}*	0	4mA typ.

*Connections to V_{CC} or V_{EE} must be less than 1Ω.

Absolute Maximum Ratings are those values beyond which device life may be impaired.

Symbol	Characteristic	Rating	Unit
V_{CC}	PECL Power Supply (V_{EE} = 0V)	0 to +8.0	Vdc
V_I	PECL Input Voltage (V_{EE} = 0V)	0 to +6.0	Vdc
V_{EE}	ECL Power Supply (V_{CC} = 0V)	-8.0 to 0	Vdc
V_I	ECL Input Voltage (V_{CC} = 0V)	-6.0 to 0	Vdc
I_{OUT}	Output Current Q_{HG}/$\overline{Q}_{HG}$ --- Continuous --- Surge Output Current Q/$\overline{Q}$ --- Continuous --- Surge	50 100 25 50	mA
T_A	Operating Temperature Range	-40 to +85	°C
T_{STG}	Storage Temperature Range	-65 to +150	°C

100K ECL DC Characteristics (V_{EE} = -3.0V to -5.5V, V_{CC} = GND)

Symbol	Characteristic	-40°C		0°C		25°C		85°C		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
V_{OH}	Output HIGH Voltage[2]	-1045	-835	-995	-835	-995	-835	-995	-835	mV
V_{OH}	Output HIGH Voltage[4]	-1085	-880	-1025	-880	-1025	-880	-1025	-880	mV
V_{OL}	Output LOW Voltage[2,4]	-1925	-1555	-1900	-1620	-1900	-1620	-1900	-1620	mV
V_{IH}	Input HIGH Voltage D/$\overline{D}$, EN (PECL) EN (CMOS/TTL)	 -1165 V_{EE}+2000	 -880 V_{CC}	 -1165 V_{EE}+2000	 -880 V_{CC}	 -1165 V_{EE}+2000	 -880 V_{CC}	 -1165 V_{EE}+2000	 -880 V_{CC}	mV
V_{IL}	Input LOW Voltage D/$\overline{D}$, EN (PECL) EN (CMOS/TTL)	 -1810 V_{EE}	 -1475 V_{EE} + 800	 -1810 V_{EE}	 -1475 V_{EE} + 800	 -1810 V_{EE}	 -1475 V_{EE} + 800	 -1810 V_{EE}	 -1475 V_{EE} + 800	mV
V_{BB}	Reference Voltage	-1390	-1250	-1390	-1250	-1390	-1250	-1390	-1250	mV
I_{IL}	Input LOW Current EN[3]	0.5		0.5		0.5		0.5		µA
I_{IH}	Input HIGH Current EN[3]		150		150		150		150	µA
I_{EE}	Power Supply Current[1]		48		48		48		54	mA

1. Specified with V_{EEP} and CS-SEL open for MLP16 and DIE. Subtract 4mA for MLP8.
2. Specified with V_{EEP} and CS-SEL connected to V_{EE} for MLP16 and DIE only.
3. Specified with EN-SEL open for MLP16 and DIE only.
4. Specified with $Q_{HG}/\overline{Q}_{HG}$ connected with 50 Ω to V_{CC} –2V for MLP 8 only.

100K LVPECL DC Characteristics (V_{EE} = GND, V_{CC} = +3.3V)

Symbol	Characteristic	-40°C		0°C		25°C		85°C		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
V_{OH}	Output HIGH Voltage[1,3]	2255	2465	2305	2465	2305	2465	2305	2465	mV
V_{OH}	Output HIGH Voltage[1,5]	2215	2420	2275	2420	2275	2420	2275	2420	mV
V_{OL}	Output LOW Voltage[1,3,5]	1375	1745	1400	1655	1480	1680	1400	1680	mV
V_{IH}	Input HIGH Voltage D/$\overline{D}$, EN (PECL)[1] EN (CMOS/TTL)	 2135 2000	 2420 V_{CC}	 2135 2000	 2420 V_{CC}	 2135 2000	 2420 V_{CC}	 2135 2000	 2420 V_{CC}	mV
V_{IL}	Input LOW Voltage D/$\overline{D}$, EN (PECL)[1] EN (CMOS/TTL)	 1490 GND	 1825 800	 1490 GND	 1825 800	 1490 GND	 1825 800	 1490 GND	 1825 800	mV
V_{BB}	Reference Voltage[1]	1910	2050	1910	2050	1910	2050	1910	2050	mV
I_{IL}	Input LOW Current EN[4]	0.5		0.5		0.5		0.5		µA
I_{IH}	Input HIGH Current EN[4]		150		150		150		150	µA
I_{EE}	Power Supply Current[2]		48		48		48		54	mA

1. For supply voltages other that 3.3V, use the ECL table values and ADD supply voltage value.
2. Specified with V_{EEP} and CS-SEL open for MLP16 and DIE. Subtract 4mA for MLP8.
3. Specified with V_{EEP} and CS-SEL connected to V_{EE} for MLP16 and DIE only.
4. Specified with EN-SEL open for MLP16 and DIE only.
5. Specified with $Q_{HG}/\overline{Q}_{HG}$ connected with 50 Ω to V_{CC} –2V for MLP 8 only.

100K PECL DC Characteristics (V_{EE} = GND, V_{CC} = +5.0V)

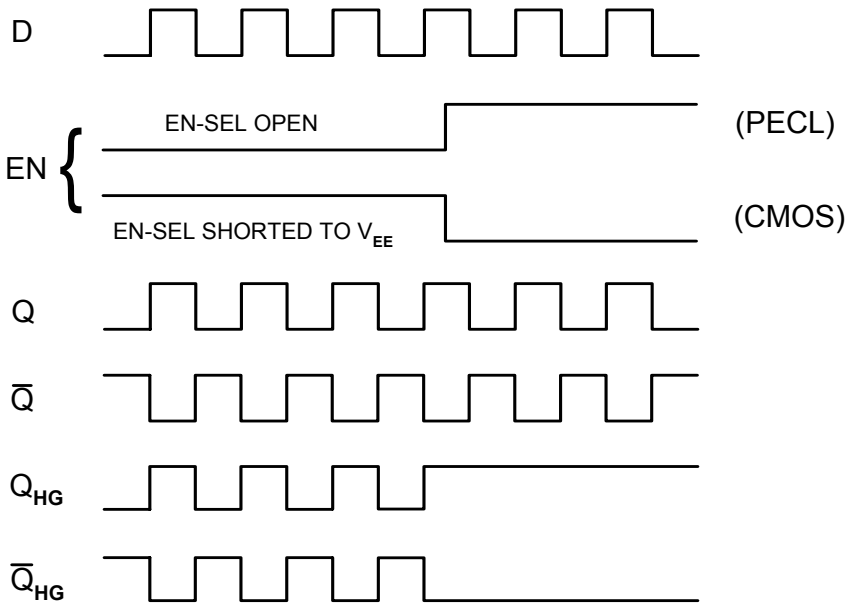
Symbol	Characteristic	-40°C		0°C		25°C		85°C		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
V_{OH}	Output HIGH Voltage[1,3]	3955	4165	4005	4165	4005	4165	4005	4165	mV
V_{OH}	Output HIGH Voltage[1,5]	3915	4120	3975	4120	3975	4120	3975	4120	mV
V_{OL}	Output LOW Voltage[1,3,5]	3075	3445	3100	3338	3100	3338	3100	3338	mV
V_{IH}	Input HIGH Voltage D/$\overline{D}$, EN (PECL)[1] EN (CMOS/TTL)	 3835 2000	 4120 V_{CC}	 3835 2000	 4120 V_{CC}	 3835 2000	 4120 V_{CC}	 3835 2000	 4120 V_{CC}	mV
V_{IL}	Input LOW Voltage D/$\overline{D}$, EN (PECL)[1] EN (CMOS/TTL)	 3190 GND	 3525 800	 3190 GND	 3525 800	 3190 GND	 3525 800	 3190 GND	 3525 800	mV
V_{BB}	Reference Voltage[1]	3610	3750	3610	3750	3610	3750	3610	3750	mV
I_{IL}	Input LOW Current EN[4]	0.5		0.5		0.5		0.5		µA
I_{IH}	Input HIGH Current EN[4]		150		150		150		150	µA
I_{EE}	Power Supply Current[2]		48		48		48		54	mA

1. For supply voltages other that 5.0V, use the ECL table values and ADD supply voltage value.
2. Specified with V_{EEP} and CS-SEL open for MLP16 and DIE. Subtract 4mA for MLP8.
3. Specified with V_{EEP} and CS-SEL connected to V_{EE} for MLP16 and DIE only.
4. Specified with EN-SEL open for MLP16 and DIE only.
5. Specified with $Q_{HG}/\overline{Q}_{HG}$ connected with 50 Ω to V_{CC} –2V for MLP 8 only.

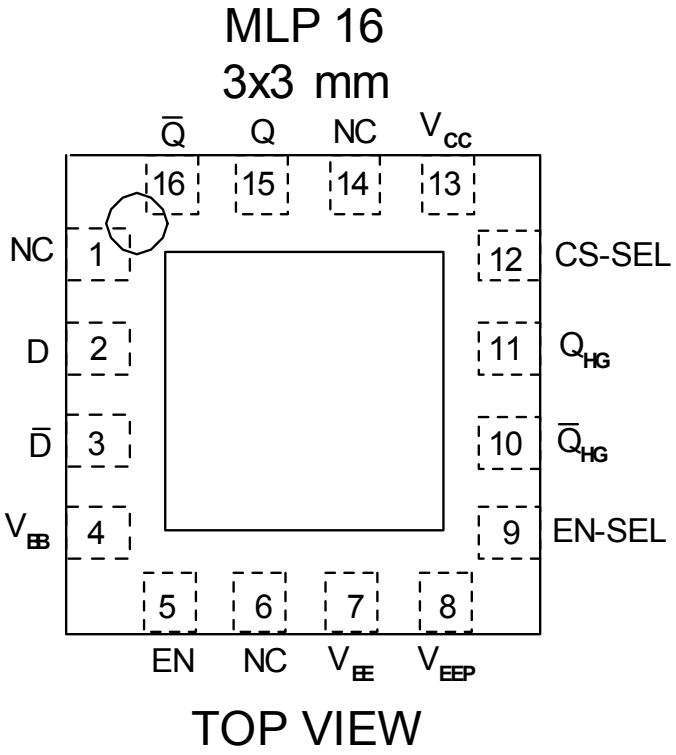
AC Characteristics (V_{EE} = -3.0V to -5.5V; V_{CC} = GND or V_{EE} = GND; V_{CC} = +3.0V to +5.5V)

Symbol	Characteristic	-40°C			0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
t_{PLH} / t_{PHL}	Propagation Delay D to Q/$\overline{Q}$ Outputs[1] (SE) D to Q_{HG}/$\overline{Q}_{HG}$ Outputs[1] (SE)			400 550			400 550			400 550			430 630	ps
t_{SKEW}	Duty Cycle Skew[2] (SE)		5	20		5	20		5	20		5	20	ps
V_{PP}	Minimum Input Swing[3] DIFF SE	80 160			80 160			80 160			80 160			mV
t_r / t_f	Output Rise/Fall Times[1] (20% - 80%)	100		260	100		260	100		260	100		260	ps

1. For MLP16 output specified with V_{EEP} and CS-SEL connected to V_{EE} with an AC coupled 50Ω load. For MLP8, AC coupled 50Ω on $\overline{Q}$ to V_{CC} –2V and DC coupled 50Ω to V_{CC} –2V on Q_{HG}/$\overline{Q}_{HG}$.
2. Duty cycle skew is the difference between a t_{PLH} and t_{PHL} propagation delay through a device.
3. V_{PP} is the minimum peak-to-peak input swing for which AC parameters guaranteed. The device has a voltage gain of ≈ 20 to Q/$\overline{Q}$ outputs and a voltage gain of ≈ 100 to Q_{HG}/$\overline{Q}_{HG}$ outputs.

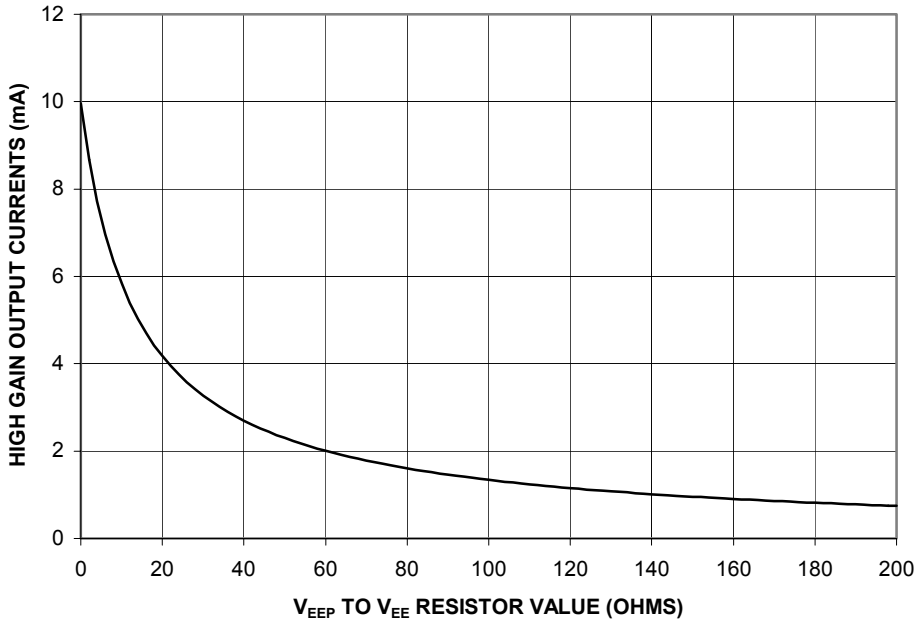


TIMING DIAGRAM

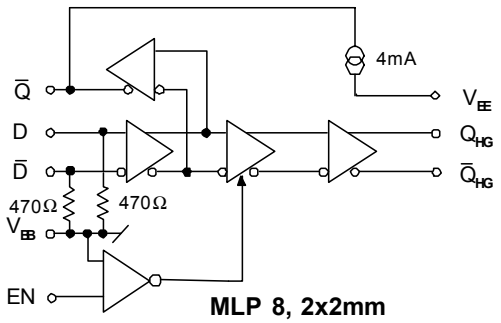


Bottom Center Pad may be left open or tied to V_{EE}

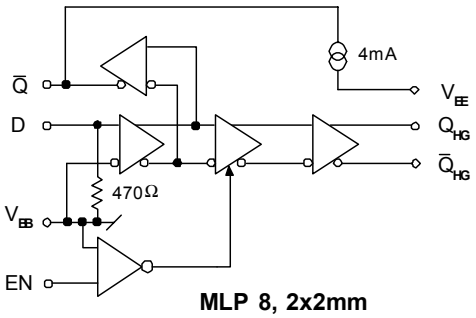
ADJUSTABLE HIGH GAIN OUTPUT CURRENT



LOGIC DIAGRAMS AND PINOUTS FOR 2x2mm PACKAGE

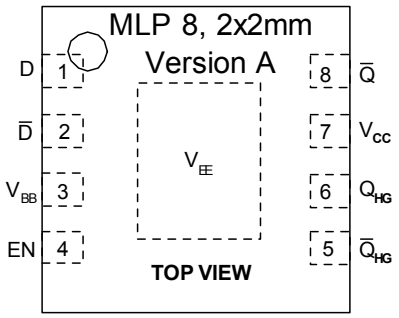


MLP 8, 2x2mm
Version A
AZ100LVEL16VTMA
AZ100LVEL16VTNA

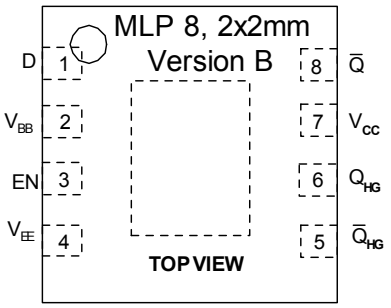


MLP 8, 2x2mm
Version B
AZ100LVEL16VTMB
AZ100LVEL16VTNB

EN operation on the versions A and B follows the PECL functionality, see Timing Diagram above.



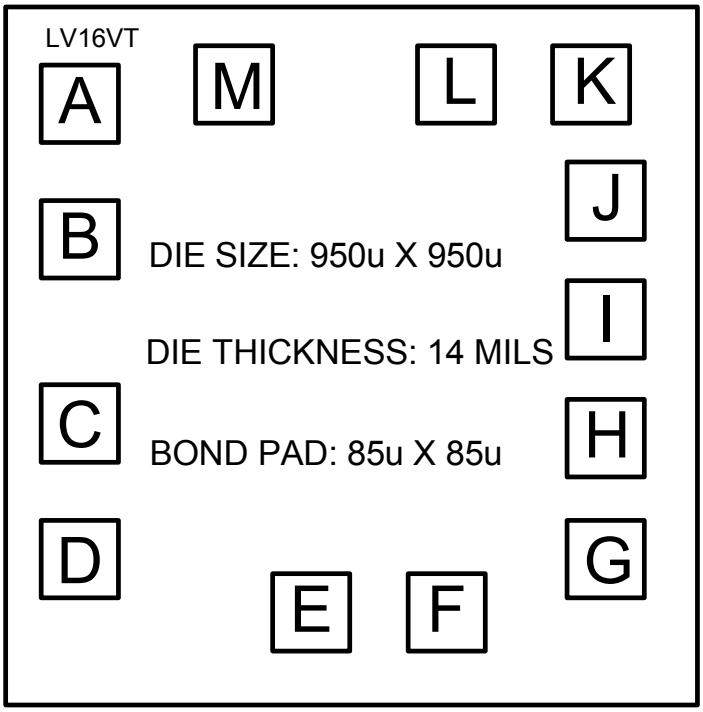
Bottom Center Pad is the V_{EE} return.



Bottom Center Pad may be left open or tied to V_{EE}. Pin 4 is the V_{EE} return.

DIE PAD COORDINATES

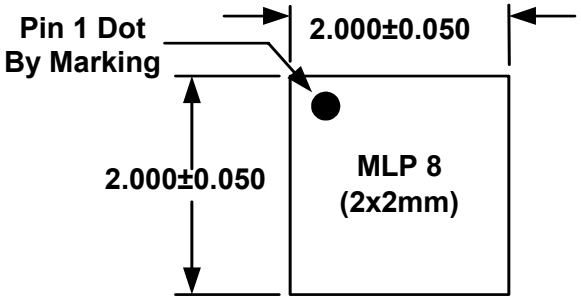
AZ100LVEL16VT DIE:



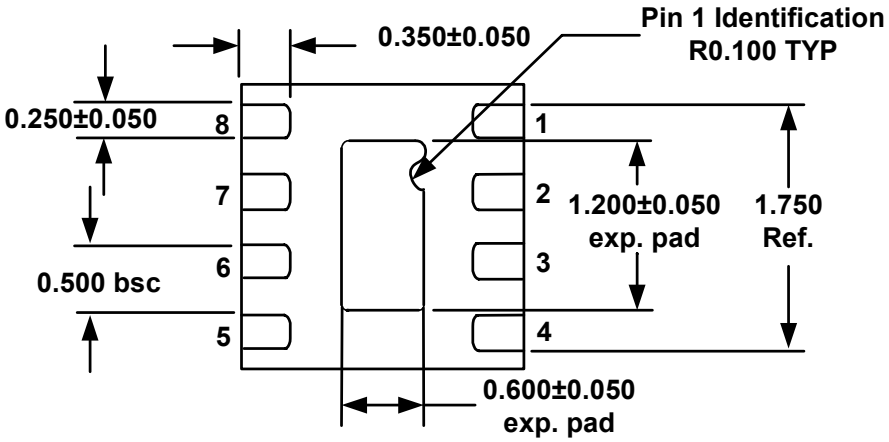
PAD CENTER COORDINATES

NAME	PAD DESIGNATION	X(Microns)	Y(Microns)
A	D	-342.5	312.5
B	$\overline{D}$	-342.5	144.5
C	V_{BB}	-342.5	-87.0
D	EN	-342.5	-255.0
E	V_{EE}	-33.5	-312.5
F	V_{EEP}	126.5	-312.5
G	EN-SEL	312.5	-248.5
H	$\overline{Q}_{HG}$	312.5	-98.5
I	Q_{HG}	312.5	51.5
J	CS-SEL	312.5	201.5
K	V_{CC}	302.5	342.5
L	Q	142.5	342.5
M	$\overline{Q}$	-140.5	342.5

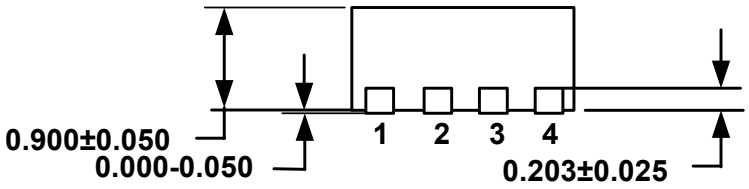
PACKAGE DIAGRAM
MLP 8 DUAL 2x2mm



TOP VIEW



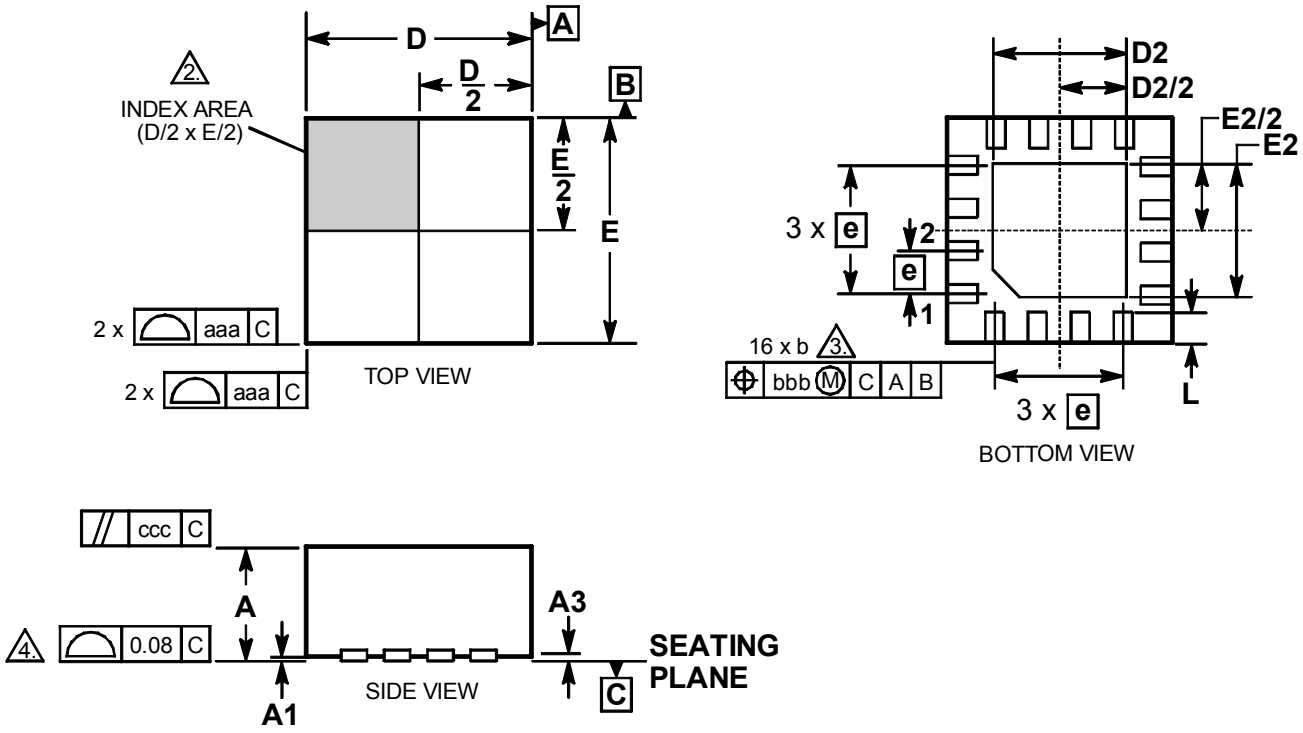
BOTTOM VIEW



SIDE VIEW

Note: All dimensions are in mm

PACKAGE DIAGRAM
MLP 16



NOTES:
1. DIMENSIONING AND TOLERANCING CONFORM TO ASME T14-1994.
2. THE TERMINAL #1 AND PAD NUMBERING CONVENTION SHALL CONFORM TO JESD 95-1 SPP-012.
3. DIMENSION b APPLIES TO METALLIZED PAD AND IS MEASURED BETWEEN 0.25 AND 0.30mm FROM THE PAD TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS

	MILLIMETERS	
DIM	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.25 REF	
b	0.18	0.30
D	2.90	3.10
D2	0.25	1.95
E	2.90	3.10
E2	0.25	1.95
e	0.50 BSC	
L	0.30	0.50
aaa	0.25	
bbb	0.10	
ccc	0.10	